SWITCHMODE™ Power Rectifier 45 V, 30 A

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 150°C Operating Junction Temperature
- 30 A Total (15 A Per Diode Leg)
- Guard-Ring for Stress Protection

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube
- This is a Pb-Free Device*

MAXIMUM RATINGS

Please See the Table on the Following Page

Semiconductor Components Industries, LLC 2010.

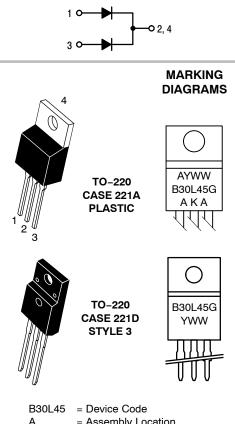
January, 2010 - Rev.



ON Semiconductor®

http://onsemi.com

DUAL SCHOTTKY **BARRIER RECTIFIERS 30 AMPERES, 45 VOLTS**



2002.0	Bornee eeue
Α	= Assembly Location
Y	= Year
WW	= Work Week
AKA	= Polarity Designator
G	= Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping
MBR30L45CTG	TO-220 (Pb-Free)	50 Units/Rail
MBRF30L45CTG	TO-220FP (Pb-Free)	50 Units/Rail

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BDTIC.com

Publication Order Number: MBR30L45CT/D

MAXIMUM RATINGS (Per Diode Leg)

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V_R) T _C = 137°C		I _{F(AV)}	15	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz)		I _{FRM}	30	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase,	60 Hz)	I _{FSM}	190	A
Operating Junction Temperature (Note 1)		TJ	–55 to +150	°C
Storage Temperature		T _{stg}	- 55 to +175	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/μs
ESD Ratings: Machine Model = C Human Body Model = 3B			> 400 > 8000	V
HERMAL CHARACTERISTICS			-	
Maximum Thermal Resistance (MBR30L45CTG) (MBRF30L45CTG)	Junction-to-Case Junction-to-Ambient Junction-to-Case	R _{θJC} R _{θJA} R _{θJC}	1.9 45 2.2	°C/W
LECTRICAL CHARACTERISTICS (Per Diode Leg)				
Maximum Instantaneous Forward Voltage (Note 2) (I _F = 15 A, T _C = 25°C) (I _F = 15 A, T _C = 125°C) (I _F = 30 A, T _C = 25°C) (I _F = 30 A, T _C = 125°C)		VF	0.50 0.44 0.61 0.60	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)		i _R	0.65 250	mA

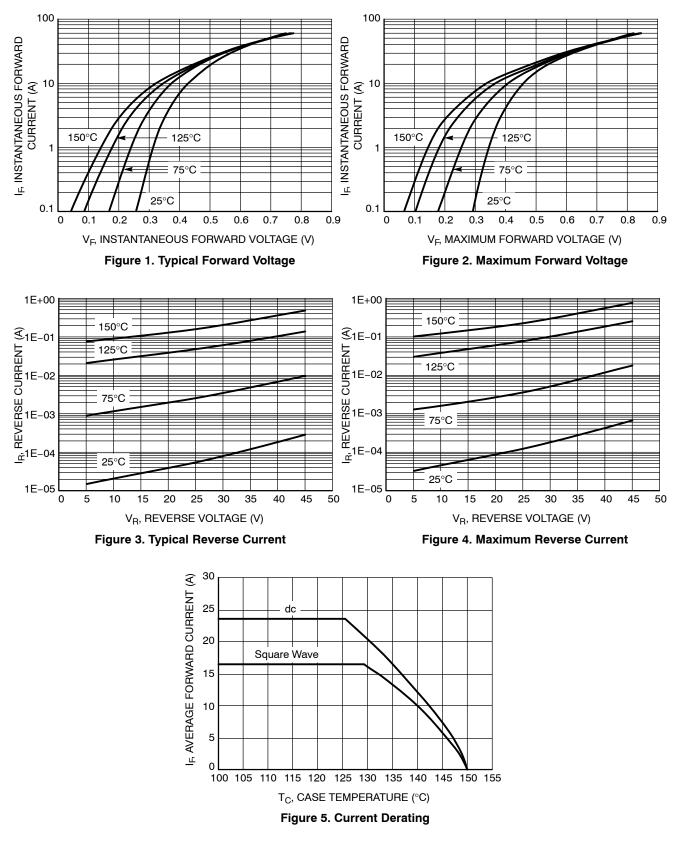
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.







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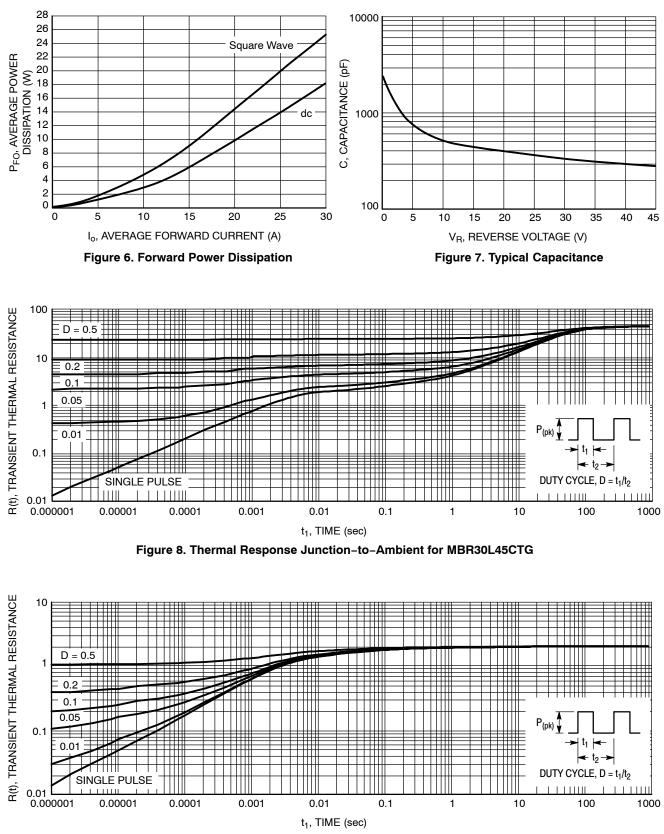


Figure 9. Thermal Response Junction-to-Case for MBR30L45CTG

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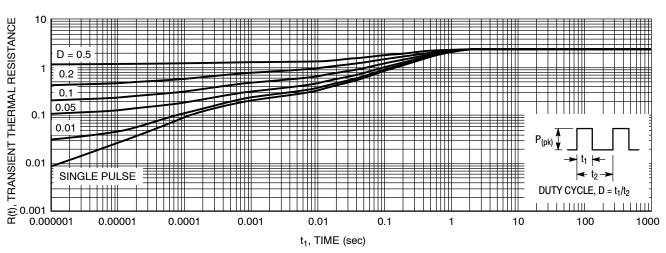
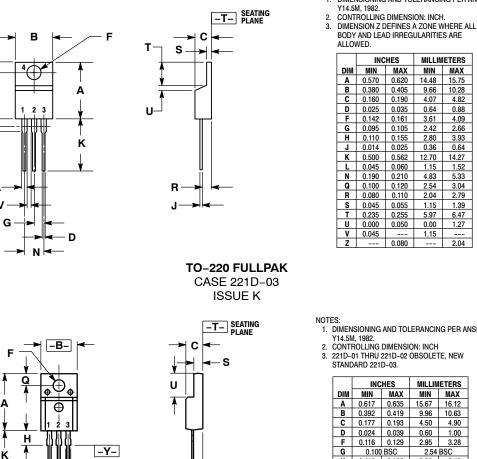


Figure 10. Thermal Response Junction-to-Case for MBRF30L45CTG

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PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI

BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Η	0.110	0.155	2.80	3.93
L	0.014	0.025	0.36	0.64
Κ	0.500	0.562	12.70	14.27
Г	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Ø	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
C	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

1. DIMENSIONING AND TOLERANCING PER ANSI

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.617	0.635	15.67	16.12
В	0.392	0.419	9.96	10.63
С	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
F	0.116	0.129	2.95	3.28
G	0.100 BSC		2.54 BSC	
Н	0.118	0.135	3.00	3.43
J	0.018	0.025	0.45	0.63
Κ	0.503	0.541	12.78	13.73
L	0.048	0.058	1.23	1.47
Ν	0.200 BSC		5.08 BSC	
Q	0.122	0.138	3.10	3.50
R	0.099	0.117	2.51	2.96
S	0.092	0.113	2.34	2.87
U	0.239	0.271	6.06	6.88

PIN 1. ANODE 2. CATHODE 3. ANODE

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